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Synthesis of Bi_2Te_3 and $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles using the novel IL $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$

Thermal decomposition of the single source precursor $(\text{Et}_2\text{Sb})_2\text{Te}$ and the reactive IL $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$ yields crystalline tetradymite-type $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ ($x = 0.25, 0.5, 0.75, 1.0$) nanoparticles at moderate temperatures without formation of Bi-rich material phases.

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Synthesis of Bi₂Te₃ and (Bi_xSb_{1-x})₂Te₃ nanoparticles using the novel IL [C₄mim]₃[Bi₃I₁₂][†]

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The novel Bi-containing reactive ionic liquid [C₄mim]₃[Bi₃I₁₂], which was synthesized in quantitative yield by equimolar reaction of BiI₃ and [C₄mim]I, was used as a novel Bi-source for the ionothermal synthesis of Bi₂Te₃ nanoparticles by reaction with (Et₂Sb)₂Te in the ionic liquid [C₄mim]I. The solid state structure of [C₄mim]₃[Bi₃I₁₂] was determined by single crystal X-ray diffraction. In addition, the ionothermal synthesis of the *single source precursor* (Et₂Sb)₂Te and [C₄mim]₃[Bi₃I₁₂] yielded the ternary (Bi_xSb_{1-x})₂Te₃ (x = 0.25, 0.5, 0.75) nanoparticles. The chemical composition and phase purity of the tetradymite-type materials were determined by EDX and XRD and the surface composition of the nanoparticles was further investigated by IR and XPS. In addition, the morphology of the nanoparticles was investigated by SEM and TEM.

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Introduction

The synthesis of highly efficient thermoelectric materials for technical application as thermoelectric generators TEG, which allow the conversion of waste thermal energy into electric energy,¹ has attracted considerable attention in recent years.² Even though radioisotope thermoelectric generators (RTG), which were used in specific technical applications such as energy supply of satellites and space probes,³ have been known since the 1950's, their low thermoelectric efficiency, which is given by the dimensionless figure of merit $ZT = (\alpha^2 \sigma / \lambda) T$ (α = Seebeck coefficient, σ = specific electrical conductivity, λ = thermal conductivity = sum of electronic λ_{e1} and lattice λ_{la} contribution, T = absolute temperature [K]), inhibited their broad technical application.

Semiconducting materials with heavy elements are very promising materials due to their high effective masses. Among many different systems, which have been investigated in the last decades, Sb₂Te₃, Bi₂Te₃ and the solid ternary solutions (Sb_xBi_{1-x})₂Te₃ are still some of the most effective materials for technical applications operating near room temperature. These materials show high electrical conductivities and high

Seebeck coefficients combined with glass-like low thermal conductivities.⁴ They are isostructural and crystallize in the tetradymite-type structure, with the Te atoms building a closed packing structure perpendicular to the *c*-axis in $R\bar{3}m:H$ and the stacking sequence *chh* in Jagodzinski-symbols. The stacking sequence ($A\gamma B\Box A\gamma BaC\Box BaC\beta A\Box C\beta$) results in the formation of double layers of edge-sharing Bi(Sb)Te₆ octahedra consisting of 5 atom layers (quintuple layer) with the sequence Te1–Bi(Sb)–Te2–Bi(Sb)–Te1 and the composition (Bi(Sb))₂Te₃. The bonding inside the quintuple layer can be described as mixed covalent-ionic, while only weak van der Waals bonding is observed between the quintuple layers.⁴

Nanostructuring has been identified in the late nineties of the last century as a promising method for increasing the thermoelectric efficiency (zT) of a given material,⁵ resulting from the decreased thermal conductivity of the material due to an efficient phonon scattering at boundaries and interfaces, and a simultaneously increased Seebeck coefficient due to both quantum confinement effects and the modification of the electronic band structure.⁶ In addition, ternary solid solutions (Bi_xSb_{1-x})₂Te₃ showed enhanced zT values compared to the corresponding binary materials (Bi₂Te₃, Sb₂Te₃) as was demonstrated for (Bi_xSb_{1-x})₂Te₃ single crystals ($z = 3.2 \times 10^{-3} \text{ K}^{-1}$ at room temperature⁷) and *p*-type (Bi_{0.2}Sb_{0.8})₂Te₃ nanocomposites (z of $3.52 \times 10^{-3} \text{ K}^{-1}$ at room temperature⁸). Poudel *et al.* reported record-high zT values of 1.4 at 373 K for bulk (Bi_xSb_{1-x})₂Te₃ with embedded nanostructures^{2a} and Xie *et al.* observed a maximum zT value of 1.56 at 300 K for the *p*-type (Bi_{0.26}Sb_{0.74})₂Te₃ material, which is roughly a 50% improvement compared to commercial Bi₂Te₃.⁹

As a consequence, the synthesis of nanoparticles and thin films of tetradymite-type materials has received increasing

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interest. Unfortunately, their strong tendency to form antisite defects, which refers to the occupation of Te sites by Bi atoms or Bi sites by Te atoms and, as a consequence, the formation of either p- or n-type doped materials, often diminish their thermoelectric performance.¹⁰ In addition, the facile incorporation of excess bismuth into Bi₂Te₃ yield Bi-rich material phases, which typically adopt sandwich-like structures of the general form (Bi_xSb_{1-x})₂Te₃, in which the quintuple layers are separated by Bi-bilayers¹¹ as can be observed in tsumoite BiTe, pilsenite Bi₄Te₃ and hedleyite Bi₇Te₃, respectively.

The synthesis of bulk and nanostructured p-type (Bi_xSb_{1-x})₂Te₃ has been widely investigated.^{2a,12} Bismuth-rich Bi₂Te₃ and (Sb_xBi_{1-x})₂Te₃ particles were obtained from the reduction of bismuth/antimony acetate with oleylamine (OA) in dodecanethiolenol and subsequent reaction with trioctyltellurophosphorane (TOPTe)¹³ as well as by reaction of TOPTe and bismuth oleate.¹⁴ In addition, hexagonal Bi₂Te₃ plates were obtained upon thermolysis of bismuth nitrate and TOPTe in octadecene and oleic acid¹⁵ and by reaction of BiCl₃ and TOPTe in thioglycolic acid in a microwave assisted synthesis.¹⁶ The resulting material, which was sub-atomically doped with sulfur, showed a remarkably high *zT* value (1.1). In addition, Reid *et al.* recently demonstrated that [BiCl₃(TeⁿBu₂)₃] is a suitable single source precursor for the MOCVD (metal organic chemical vapor deposition) deposition of high-quality Bi₂Te₃ thin films.¹⁷ In addition to the widely applied Te source TOPTe, bis(triethylsilyl)tellurane (Et₃Si)₂Te has been demonstrated to be a promising low-temperature Te-precursor. Sb₂Te₃ and Bi₂Te₃ thin films were deposited by ALD process (atomic layer deposition)¹⁸ and by low-temperature MOCVD process.¹⁹ In addition, (Et₃Si)₂Te was successfully applied for the wet chemical synthesis of multiple Bi-Te phases including Bi₂Te₃.²⁰

Due to our general interest in thermoelectric materials, we started only recently to investigate both gas phase deposition of thin films using ALD^{18b,c} and MOCVD processes^{19c,d} as well as wet chemical approaches for the synthesis of Sb₂Te₃ and Bi₂Te₃ nanoparticles in organic solvents^{20,21} and in ionic liquids (ILs). ILs were shown to be very promising solvents for the synthesis of Sb₂Te₃ nanoparticles with very high *zT* values of up to 1.5.²² However, the limited thermal stability of metal organic bismuth precursors such as bismuth amides or bismuth alkyl compounds often resulted in the formation of elemental bismuth or Bi-rich material phases.²⁰ Therefore, we became interested in the development of alternate Bi precursors, which should be thermally stable to avoid simple thermal decomposition but whose reactivity should still be high enough to produce the desired materials at rather low temperatures.

We herein report on the synthesis and solid state structure of the novel reactive IL [C₄mim]₃[Bi₃I₁₂] and its promising potential to serve as alternate Bi source for the synthesis of phase-pure binary (Bi₂Te₃) and – together with the single source precursor (Et₂Sb)₂Te – ternary [(Bi_xSb_{1-x})₂Te₃] bismuth telluride nanoparticles in an IL-based wet chemical approach. The composition, phase purity and morphology of the result-

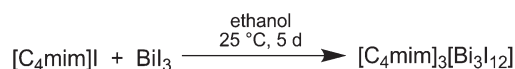
ing tetradymite-type nanoparticles were investigated by IR, EDX, XPS, XRD, SEM and TEM.

Results and discussion

Our previous studies on the synthesis of Bi₂Te₃ nanoparticles in organic solvents showed a strong tendency for the formation of Bi-rich materials, most likely resulting from the thermal lability of the Bi precursor. Therefore, we became interested in a more stable Bi precursor and began to investigate the use of complex bismuth halide anions such as [Bi₃I₁₂]³⁺, which have been synthesized in the past.^{23–26} Hence, we synthesized the novel reactive IL [C₄mim]₃[Bi₃I₁₂] **1** in high yield by reaction of [C₄mim]I and BiI₃ (Scheme 1).

1, which shows a melting point of 98 °C, was obtained as a bright yellow powder at ambient temperature. The yellow color of [C₄mim]₃[Bi₃I₁₂] **1** was found to intensify upon cooling to –196 °C; whereas it turns red and finally becomes metallic-like, almost black-purple upon heating to 250 °C (Fig. S8†). Both processes are fully reversible. Even though the reason for this thermochromic behavior is not yet clear, we believe that the color change upon cooling and heating results from a phase transition of **1**. Phase transition reactions are well known for bismuth(III)iodides, for which more than 60 compounds have been structurally characterized and which show a large structural diversity. To date, almost 20 different structural types have been reported.²⁷ The structures were found to largely depend on the specific cation. A templating effect of the cations has been identified as the major structure determining factor that induces the formation of various metal-halide networks. In the case of (2-MIm)BiI₄, a change of the electron lone pair activity of the bismuth atom was also found to play a major role in the phase transition mechanism.^{27b} A DSC study revealed an exothermic process around –50 °C and the melting point was also observed (Fig. S9†).

1 is highly soluble in strong polar, aprotic solvents such as acetonitrile and DMSO and barely soluble in less polar solvents, *e.g.* ethanol and methanol, while it is insoluble in non-polar solvents such as pentane and hexane as well as in water. In comparison to the NMR spectra of [C₄mim]I the aromatic signals of **1** are high-field shifted by 0.2 ppm in the ¹H NMR and by 4 ppm in the ¹³C NMR spectra, while the resonances due to the aliphatic groups show a low-field shift by the same amounts (Fig. S1 and S2†), indicating stronger electronic interactions between the positively charged aromatic system with the [Bi₃I₁₂]^{–3} anion compared to the iodine anion, hence resulting in an increased electron density in the aromatic system but a decreased electron density in the aliphatic chain. The IR spectrum of **1** shows the typical absorption



Scheme 1 Synthesis of [C₄mim]₃[Bi₃I₁₂] **1**.



Table 1 Chemical composition of the Bi₂Te₃ nanocrystals determined by EDX spectroscopy

	[C ₄ mim] ⁺ ^a	[C ₄ mim]I/OA ^b	[C ₄ mim]I/OA ^c
Bi (%)	29.00 ± 1.00	40.73 ± 1.41	38.93 ± 1.25
Te (%)	71.00 ± 1.64	59.27 ± 1.36	61.07 ± 1.33

^a Thermal treatment to 150 °C. ^b Thermal treatment to 150 °C with OA.^c Thermal treatment to 150 °C microwave irradiation.

bands for the [C₄mim]⁺ cation and additional sharp absorption bands between 1150 cm⁻¹ and 930 cm⁻¹, which can be ascribed to the Bi–I-stretching vibrations (Fig. S3†).[‡]

Single crystals of **1** were obtained by re-crystallization from ethanolic solution. [C₄mim]₃[Bi₃I₁₂] crystallises in the monoclinic space group *P*2₁/*c*. The asymmetric unit comprises three cations at general positions and two anions at special positions (centre of inversion) as was previously observed for the majority of the known [Bi₃I₁₂] polyanions. The two independent anions lead to an occupation of all vertices and face-centres of the unit cell similar to a cubic closest packing of spheres. However, their anisotropic shape – they are best described as a linear arrangement of three face-sharing BiI₆ octahedra – prevents cubic symmetry. The cations fill the voids where the ones labelled X1*x* and X3*x* can be found in the pseudo-tetrahedral gap, while the X2*x*-labelled and its symmetry equivalent share the pseudo-octahedral gap.

Bond lengths and angles of the cations show typical values. The conformation of the butyl group of the cations differs depending on the space available to fill (Cx5–Cx6–Cx7–Cx8: –170(2)° (*x* = 1), 66(2)° (*x* = 2), 175(2)° (*x* = 3)). The range of Bi–I bond lengths matches well with those previously reported by Carmalt *et al.* and others for [Bi₃I₁₂] and [Bi₄I₁₆] polyanions.^{23–25} These polyanions can be described as central BiI₆^{3–} octahedral units with neutral BiI₃ moieties capping two of its *trans* oriented faces. The independent anions are roughly perpendicular to one another (Bi11...Bi12/Bi21...Bi22 74.22(1)°) and parallel to the (100) plane. Inter-halide interactions lead to the formation of layers parallel to this plane (Table S1†). These layers are interconnected by non-classical hydrogen bonds between anion and cations (Table S2†).²⁶

Synthesis of Bi₂Te₃ nanoparticles

Thermolysis of (Et₃Si)₂Te and [C₄mim]₃[Bi₃I₁₂] in a solution of 10 mL of [C₄mim]I at 150 °C yielded a black precipitate, which was isolated by centrifugation and purified by repeatedly washing with acetonitrile and hexane (3*x*). The elemental composition of the material as determined by EDX proved the formation of slightly Te-rich Bi₂Te₃ materials (Table 1). NMR spectroscopic studies (¹H, ¹³C) showed that the thermolysis not only occurred with the expected formation of Et₃SiI but

[‡] ¹H, ¹³C NMR and IR spectra of [C₄mim]I and [C₄mim]₃[Bi₃I₁₂] **1**; *in situ* NMR spectroscopic studies of the reaction of (Et₃Si)₂Te and **1**; thermal behavior of **1** upon heating and cooling; central structural parameters of **1** and EDX results from STEM spot analyses on single crystals.

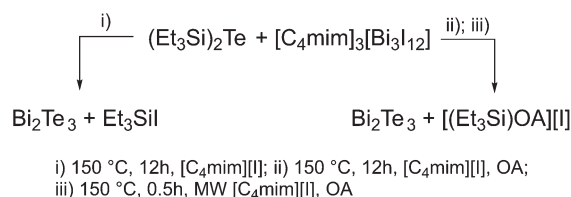
also with formation of hexaethyldisilane Si₂Et₆ (Fig. S4a–c†), whose formation points to a homolytic cleavage of the weak Te–Si bond. As formed Et₃Si radicals then easily recombine to Si₂Et₆. These findings also explain the presence of small amounts of elemental Te in the resulting material, which can be removed by washing the material with TOP as was previously demonstrated.²⁰ In contrast, thermolysis of (Et₃Si)₂Te and [C₄mim]₃[Bi₃I₁₂] in a solution of 10 mL [C₄mim]I and 3 mL oleylamine (OA) at 150 °C yielded pure Bi₂Te₃ nanoparticles according to EDX studies (Scheme 2). We recently demonstrated that OA reacts with (Et₃Si)₂Te at ambient temperature with formation of silylamine (Et₃SiOA) and tellurium polyanions,²⁸ which then consequently react with [C₄mim]₃[Bi₃I₁₂] with the formation of Bi₂Te₃.

We also investigated a microwave-assisted synthesis, since this technique was found to be very promising for the generation of pure Sb₂Te₃ nanoparticles.²² A solution of (Et₃Si)₂Te and [C₄mim]₃[Bi₃I₁₂] in 10 mL of [C₄mim]I and 3 mL of OA was heated to 150 °C by microwave irradiation and the resulting particles were treated as mentioned before. However, slightly Te-rich materials were formed according to EDX studies (Table 1).

We further investigated the presence of any kind of organic molecules, *i.e.* solvent molecules or capping agents, on the surface of the materials as-obtained from thermolysis reactions of the precursors in [C₄mim]I and OA. IR spectroscopy clearly demonstrated that the resulting Bi₂Te₃ nanoparticles do not contain OA (capping agent) on the surface as can clearly be seen by comparing the IR spectra of the nanoparticles and that of pure OA (Fig. 2). In addition, neither the IL nor acetonitrile (washing solvent) bind to the nanoparticles. According to these IR studies, the nanoparticles are considered to be almost capping-agent free.

The resulting materials were investigated by powder X-ray diffraction (PXRD), which clearly proved the formation of Bi₂Te₃ in all experiments (Fig. 3). The peaks can be indexed on the basis of phase-pure Bi₂Te₃ (PDF 15-863), but the materials obtained in ionothermal syntheses in [C₄mim]I in the absence of oleylamine as well as in microwave assisted reactions in [C₄mim]I and OA showed additional reflexes at 23°, 38°, and 44°, respectively, which indicate the presence of small impurities of elemental tellurium. In contrast, the ionothermal synthesis in a mixture of [C₄mim]I and oleylamine yielded phase pure Bi₂Te₃.

The lattice parameters for the nanosized Bi₂Te₃ particles, which were refined to *a* = 4.388(8) Å, *c* = 30.517(7) Å and

**Scheme 2** Synthesis of Bi₂Te₃ nanoparticles.

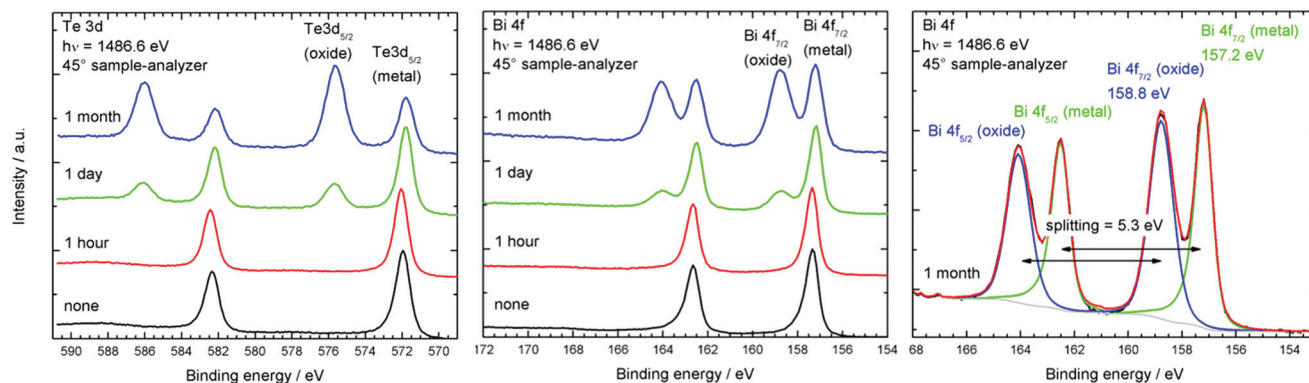


Fig. 4 Change of the Bi 4f and Te 3d XPS signals of Bi_2Te_3 nanoparticles upon exposure to air.

Table 3 Percentage of oxidised metal atoms after exposure to air as determined by XPS

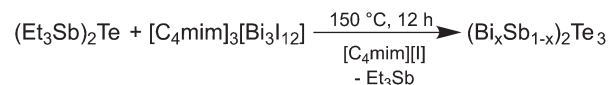
Exposure to air	Bi-oxide/%	Te-oxide/%
None	0	0
1 hour	0	0
1 day	22	27
1 month	53	65

formation of Bi-rich materials such as BiTe or Bi_4Te_3 , which was often observed in reactions of metal organic precursors as a result of the often thermally rather unstable Bi precursors, is completely avoided in the reaction with the reactive Te-source $(\text{Et}_3\text{Si})_2\text{Te}$, indicating a constant release of Bi under the specific reaction conditions.

Synthesis of ternary $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles

After the successful synthesis of phase-pure Bi_2Te_3 nanoparticles, we became interested in the synthesis of ternary solid solutions of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$. Since the thermolysis of the single source precursor $(\text{Et}_2\text{Sb})_2\text{Te}$ was previously established for the synthesis of highly stoichiometric Sb_2Te_3 nanoplates,^{21,22} we investigated its thermolysis in the presence of different amounts of the reactive IL $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$ **1** in 10 mL of $[\text{C}_4\text{mim}]\text{I}$. After thermolysis at 150 °C, the resulting black solid was isolated by centrifugation and purified by repeatedly washing with acetonitrile (Scheme 3).

Ternary materials of the general type $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ were obtained in all cases, even though they showed a slight tellurium deficit. In addition, a general trend for bismuth-rich particles was observed (Table 4). The reactions probably proceed



Scheme 3 Thermolysis of the single source precursor $(\text{Et}_2\text{Sb})_2\text{Te}$; reaction of $(\text{Et}_2\text{Sb})_2\text{Te}$ and $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$ **1** for the synthesis of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles.

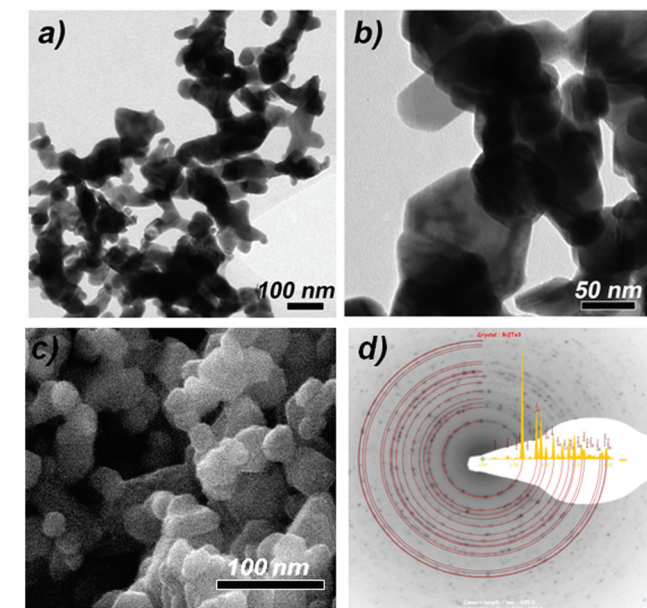


Fig. 5 TEM bright field images (a, b); SEM image (c) and contrast inverted selected area electron diffraction pattern of Bi_2Te_3 (Philips CM30 T @300 keV) and simulated ring pattern as overlay SAED (d) of Bi_2Te_3 nanoparticles.³²

taken from a crystal covered region gives a powder ring pattern with d -values as expected for Bi_2Te_3 .

The synthesis of phase-pure Bi_2Te_3 nanoparticles proves the promising potential of the novel reactive IL $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$ **1** to serve as a Bi-source in materials synthesis. The

Table 4 EDX results from the $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles

x	Bi (%)	Sb (%)	Te (%)
0.25	12.4 ± 0.6	28.3 ± 0.9	59.3 ± 1.8
0.5	22.5 ± 0.9	19.3 ± 0.5	58.2 ± 1.5
0.75	30.1 ± 1.2	11.3 ± 0.5	58.7 ± 1.6



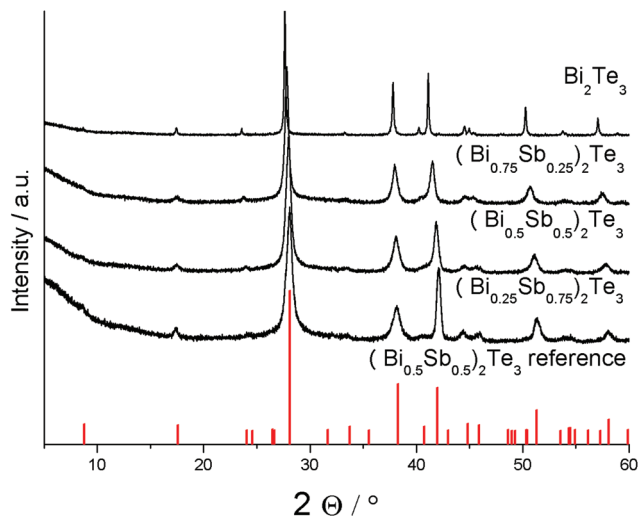


Fig. 6 Powder X-ray diffractogram of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ ($x = 0.25, 0.5, 0.75, 1$) nanoparticles and reference for $(\text{Bi}_{0.5}\text{Sb}_{0.5})_2\text{Te}_3$ (PDF 072-1853).³³

with the initial formation of small Sb_2Te_3 nanoparticles, in which the antimony content is consequently substituted by bismuth successively provided from the reactive IL 1.

PXRD studies proved the formation of phase pure ternary materials $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ (Fig. 6). The successful substitution of bismuth by antimony in the tetradymite-type material can be monitored by a slight shift of the reflections toward higher angles with increasing antimony concentration, resulting in decreasing lattice parameters as was expected due to the replacement of the large bismuth atoms by smaller antimony atoms. This is confirmed by the refinement of the lattice parameters, which show a monotonically decreasing cell volume (Table 5).

Compared to the phase-pure Bi_2Te_3 nanoplates, the XRDs of the as-prepared ternary solid solutions $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ showed increasing peak broadening, clearly indicating a steadily decreasing size of the crystalline domains with increasing bismuth concentration (Fig. 6). In addition, anisotropic peak broadening becomes more dominant, underlining the preferential growth along the ab -plane perpendicular to the c -axis, which manifests itself in a relatively sharp (110) reflection at 41.12° (2θ) compared to the other reflections, *i.e.* the neighboring (1010) reflex at 37.8° .

Table 5 Refined lattice parameters and crystallite sizes for $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles

x	a [Å]	c [Å]	V [Å ³]	Size ^a [nm]
1	4.388(8)	30.517(7)	509.0(7)	38.3(9)
0.75	4.360(6)	30.449(2)	501.4(1)	33.6(6)
0.5	4.319(9)	30.496(2)	492.8(6)	25.7(2)
0.25	4.291(9)	30.580(4)	487.8(3)	22.9(3)

^aThe determination of the crystal size of anisotropic particles such as thin plates by using the Scherrer equation is always problematic. Values should therefore be taken with care.

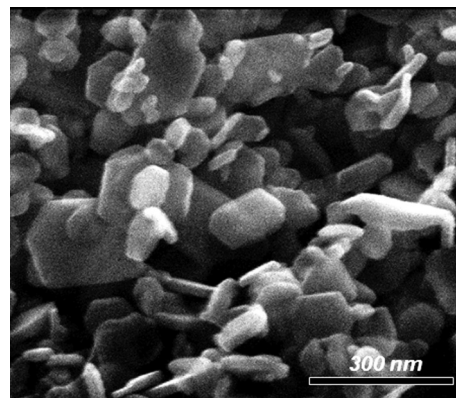


Fig. 7 SEM image of $(\text{Bi}_{0.5}\text{Sb}_{0.5})_2\text{Te}_3$.

As was observed for the Bi_2Te_3 nanoplates, the as-prepared $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ materials also consist of hexagonal nanoplates, which again are highly agglomerated. The average size of the nanoparticles according to SEM studies ranges from roughly 50 nm to 100 nm (Fig. 7).

TEM studies confirm the hexagonal plate-like shape of the $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ materials with the growth direction perpendicular to the c -axis and a broad size distribution. Although some of the larger hexagonal plates consist of an intergrowth of several crystalline domains, crystals from 10 to 200 nm in size are present in each of the $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ materials (Fig. 8a–c). EDX spot analyses in the STEM mode on single crystals (Table S3†) confirm the composition corresponding to the sum formula $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ with $x = 0.25, 0.5$ and 0.75 and

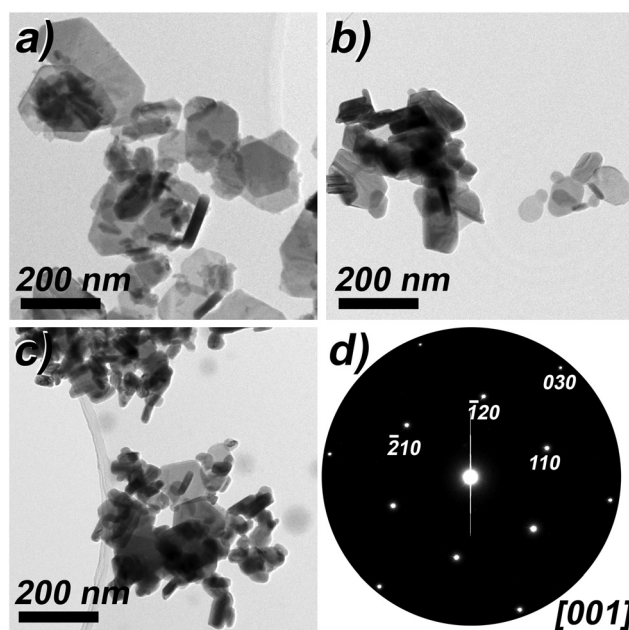


Fig. 8 TEM bright field images of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ with (a) $x = 0.25$; (b) $x = 0.5$; (c) $x = 0.75$. (d) Electron diffraction pattern of a $(\text{Bi}_{0.25}\text{Sb}_{0.75})_2\text{Te}_3$ crystal along c^* .



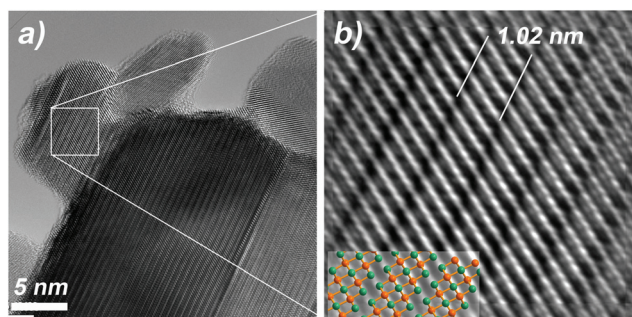


Fig. 9 (a) HRTEM bright field image of $(\text{Bi}_{0.75}\text{Sb}_{0.25})_2\text{Te}_3$ in [100] orientation; (b): Fourier filtered cutout with ball and stick model of $(\text{BiSb})_2\text{Te}_3$ as overlay (green: Te, orange: Bi, Sb).

agree with those summarized in Table 4, which were obtained from big agglomerates.

Fig. 8d shows an electron diffraction (ED) pattern of $(\text{Bi}_{0.25}\text{Sb}_{0.75})_2\text{Te}_3$ in [001] orientation. The d -values of the {100} and {030} reflections are 2.19 Å and 1.22 Å, respectively, and agree with the lattice parameters from PXRD and with the reflection conditions for space group $R\bar{3}m:H$. The presence of Bi and Sb in small volumes proven by spot EDX and the absence of any super-structure reflections in the ED-patterns reveal the random distribution of antimony and bismuth on the cation positions of the tetradymite-type structure.

Unfortunately, HRTEM studies of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ perpendicular to the c -axis, which enables the depiction of the stacking of the quintuple Bi_2Te_3 layers, was difficult to perform since the plate-like crystals were predominantly found lying in [001] orientation or they were most often too thick for HRTEM, when the orientation was perpendicular to the c -axis. Fig. 9 shows a HRTEM image of $(\text{Bi}_{0.75}\text{Sb}_{0.25})_2\text{Te}_3$ in [100] orientation. Although the atom columns are not well resolved, the stacking of the quintuple layers of 10.2 Å is found in all areas. This indicates that no additional Bi-bilayers are present and confirms the Bi_2Te_3 -type of structure.

Experimental

All synthetic procedures including the synthesis of the IL as well as all thermolysis experiments were performed under inert gas conditions (Ar atmosphere) in a glovebox or using standard Schlenk techniques. Acetonitrile (99.9%, Extra Dry, Acros organics), ethanol (J. T. Baker 98%) and 1-iodobutane (99%, Acros organics) were commercially available and used as received, while ethyl acetate (J. T. Baker) was redistilled prior to use. Solvents were carefully dried according to standard procedures and degassed prior to use. $(\text{Et}_2\text{Sb})_2\text{Te}$ was prepared according to the literature method.³⁴ Melting points were determined with an Electrothermal IA9300 digital melting point instrument from ThermoFisher Scientific.

Synthesis of 1-butyl-3-methyl-imidazolium iodide $[\text{C}_4\text{mim}]\text{I}$

22 mL (0.276 mol) 1-methylimidazole (99%, Sigma Aldrich) was dissolved in 100 mL of acetonitrile and 1-iodobutane (0.308 mol, 35 mL) was added dropwise in the dark at 0 °C. The solution was stirred at ambient temperature for 12 h and then all volatiles were removed under dynamic vacuum. The resulting residue was washed with 150 mL of ethyl acetate. After removal of the solvent, the remaining yellowish oil was dried for 72 h under dynamic vacuum at 50 °C.

Yield: 59.47 g (81%). ^1H NMR (300 MHz, 25 °C, DMSO- d_6): δ (ppm) 9.14 (s, 1H), 7.76 (dt, $^1J_{\text{H-H}} = 13.5$ Hz, $^2J_{\text{H-H}} = 1.7$ Hz, 2H), 4.19 (t, $^3J_{\text{H-H}} = 7.2$ Hz, 2H), 3.88 (s, 3H), 1.79 (dt, $^1J_{\text{H-H}} = 14.8$ Hz, $^2J_{\text{H-H}} = 7.5$ Hz, 2H), 1.29 (m, 2H), 0.93 (t, $^3J_{\text{H-H}} = 7.3$ Hz, 3H).

Synthesis of $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$ 1

14.91 g (0.561 mol) $[\text{C}_4\text{mim}]\text{I}$ and 27.57 g (0.468 mol) BiI_3 were added to 500 mL ethanol and the resulting suspension was stirred at ambient temperature for 5 d. The resulting bright yellow solid was separated *via* filtration, washed with 100 mL of ethanol and carefully dried for 72 h under dynamic vacuum at ambient temperature.

Yield: 30.87 g (77.16%). Melting point: 98 °C. Elemental analysis (EDX): Bi: 19.79 ± 0.95 at%, I: 80.21 ± 1.74 at%. ^1H NMR (300 MHz, 25 °C, DMSO- d_6): δ (ppm) 9.11 (s, 1H), 7.73 (dt, $^1J_{\text{H-H}} = 20.2$ Hz, $^2J_{\text{H-H}} = 1.8$ Hz, 2H), 4.16 (t, $^3J_{\text{H-H}} = 7.2$ Hz, 2H), 3.85 (s, 3H), 1.76 (m, 2H), 1.29 (m, 2H), 0.93 (t, $^3J_{\text{H-H}} = 7.3$ Hz, 3H).

Synthesis of Bi_2Te_3 nanoparticles

3.4 g (3.9 mmol) of **1** was dissolved in 10 mL of $[\text{C}_4\text{mim}]\text{I}$ or in a mixture of 10 mL of $[\text{C}_4\text{mim}]\text{I}$ and 3 mL of oleylamine in a centrifuge tube and the mixture was stirred for 1 h at 100 °C. 1.24 g (3.47 mmol) $(\text{Et}_2\text{Sb})_2\text{Te}$ were then added and the resulting black suspension was stirred for 12 h at 150 °C. The resulting colloidal solutions were centrifuged (2500 rpm), washed with 6×15 mL acetonitrile and 2×15 mL hexane, and dried at room temperature under vacuum.

Synthesis of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles

In a centrifuge tube, an appropriate amount (see Table 6) of $[\text{C}_4\text{mim}][\text{Bi}_3\text{I}_{12}]$ was dissolved in 2 mL $[\text{C}_4\text{mim}]\text{I}$ and stirred for 1 h at 100 °C. 137 μL (1.44 mmol) $(\text{Et}_2\text{Sb})_2\text{Te}$ were then added and the solution was stirred for 12 hours at 150 °C. The resulting black particles were washed with 6×15 mL acetonitrile.

Table 6 Amount of $[\text{C}_4\text{mim}]_3[\text{Bi}_3\text{I}_{12}]$ **1** used for the synthesis of $(\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$ nanoparticles

x	m 1 [mg]	n 1 [mmol]
0.25	103	0.04
0.5	205	0.08
0.75	308	0.12



Single crystal X-ray diffraction

Crystallographic data of **1** were collected on a Bruker D8 Kappa APEX2 diffractometer (MoK α radiation, $\lambda = 0.71073 \text{ \AA}$) at 100(1) K: [C₂₄H₄₅Bi₃I₁₂N₆], $M = 2567.40$, red crystal, (0.145 × 0.094 × 0.047 mm); monoclinic, space group $P2_1/c$; $a = 17.5900(9) \text{ \AA}$, $b = 15.9186(7) \text{ \AA}$, $c = 19.3836(9) \text{ \AA}$; $\alpha = 90^\circ$, $\beta = 96.503(3)^\circ$, $\gamma = 90^\circ$, $V = 5392.6(4) \text{ \AA}^3$; $Z = 4$; $\mu = 16.658 \text{ mm}^{-1}$; $\rho_{\text{calc}} = 3.162 \text{ g cm}^{-3}$; 87 677 reflexes ($\theta_{\text{max}} = 28.408^\circ$), 13 458 unique ($R_{\text{int}} = 0.1193$); 415 parameters; largest max./min. in the final difference Fourier synthesis $2.683 \text{ e \AA}^{-3}/-2.694 \text{ e \AA}^{-3}$; max./min. transmission 0.41/0.75; $R_1 = 0.0423$ ($I > 2\sigma(I)$), $wR_2 = 0.0864$ (all data). The solid-state structure of **1** is shown in Fig. 1. The structure was solved by direct methods (SHELXS-97)³⁵ and refined anisotropically by full-matrix least-squares on F^2 (SHELXL-2014).³⁶ Absorption corrections were performed numerical based on indexed faces (Bruker AXS APEX2). Hydrogen atoms were refined using a riding model or rigid methyl groups.

The crystallographic data of **1** (excluding structural factors) have been deposited with the Cambridge Crystallographic Data Centre as supplementary publication no. CCDC 1479636.

Instrumentation

IR spectroscopy. IR spectra were recorded in a glovebox using an ALPHA-T FT-IR spectrometer equipped with a single reflection ATR sampling module.

NMR spectroscopy. ¹H (300 MHz) and ¹³C{¹H} (75.5 MHz) NMR spectra (δ in ppm) were recorded using a Bruker Avance DPX-300 spectrometer and were referenced to internal DMSO-d₆ (¹H: $\delta = 2.50$; ¹³C: $\delta = 39.52$).

XPS. XPS studies were performed using a Versaprobe IITM (Ulvac-Phi) with monochromatic Al K α light at 1486.6 eV photon energy. The emission angle between the analyzer and sample is 45°. The Cu 2p signal at 932.67 eV binding energy of a sputter-cleaned Cu foil was used as the binding energy reference. The foil and the powder were put onto insulating double-sided tape and charging effects were compensated using a dual-beam neutralizing approach using electrons and slow moving argon ions.

Electron microscopy. Particle size and morphology as well as the elemental composition of the powders were analyzed by scanning electron microscopy (SEM) using a Jeol JSM 6510 microscope equipped with a Bruker Quantax 400 spectrometer (EDX, chemical composition). TEM studies were conducted on transmission electron microscopes: (i) FEI Philips CM30 T/LaB₆ operated at 300 kV and (ii) FEI-Philips CM300 UT/FEG operated at 300 kV. Both microscopes are equipped with Gatan CCD's for image recording and with Thermo NSS systems for EDS analysis using a Si(Li) Nanotracer and a HP-Ge EDS detector, respectively. The samples were prepared on perforated carbon foils without further grinding.

Powder X-ray analysis. PXRD patterns were obtained at ambient temperature (25 ± 2 °C) using a Bruker D8 Advance powder diffractometer in the Bragg-Brentano mode with Cu K α radiation ($\lambda = 1.5418 \text{ \AA}$, 40 kV, and 40 mA). The powder

samples were investigated in the range of 5 to 90° 2 θ with a step size of 0.01° 2 θ and a counting time of 0.3 s. Rietveld refinement was performed with the program package TOPAS 5.0 from Bruker. The instrumental correction was determined using LaB₆ powder from NIST (National Institute of Standards and Technology) as the standard reference material and taken into account for each refinement.

Conclusions

The novel Bi source [C₄mim]₃[Bi₃I₁₂] **1** containing the complex [Bi₃I₁₂] trianion was synthesized and structurally characterized. **1** is a promising Bi source for the preparation of phase pure Bi₂Te₃ material in ILs using ionothermal synthesis. The formation of Bi-rich material phases, as has been often described for other synthetic routes, is completely avoided. The Bi₂Te₃ nanoparticles are surfactant free according to IR spectroscopic studies and are easily oxidised upon exposure to air.

In addition, co-thermolysis of **1** with the single source precursor (Et₂Sb)₂Te in different molar ratios in [C₄mim]₃I allowed for the synthesis of a whole range of ternary solid solutions of the general formula (Bi_xSb_{1-x})₂Te₃, which were characterized by XRD, SEM, EDX and TEM.

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